NSN 5961-00-139-6629

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Inclosure Material:
Metal
Overall Length:
0.830 inches
Function For Which Designed:
Zener diode
End Application:
An/apq-148 radar; ea-6b prowler aircraft
Mounting Facility Quantity:
1
Electrode Internally-electrically Connected To Case:
Cathode
Mounting Method:
Threaded stud
Overall Width Across Flats:
0.250 inches
Thread Size:
0.138 inches
Criticality Code Justification:
Feat
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
11.0 breakdown voltage, dc and 14.0 breakdown voltage, dc and 11.2 reverse voltage, instantaneous
Current Rating Per Characteristic:
175.00 milliamperes source cutoff current horsepower metric
Power Rating Per Characteristic:
10.0 watts small-signal input power, common-collector preset
Maximum Operating Tempurature Per Measurement Point:
175.0 degrees celsius ambient air
Special Features:
Weapon system essential
Precious Material And Location:
Solder tab plated gold
Test Data Document:
95542-941-032 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.
excludes any specification, standard or other document that may be referenced in a basic governing drawing)
Thread Series Designator:
Unc
Terminal Type And Quantity:
1 solder stud and 1 tab, solder lug and 1 threaded stud
Shelf Life:

N/a

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Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

A110a0